

0.152um			Mar-4 TMMH15 Fab10 Jerry			Jun-3 TMMH16 Fab10 Shirley							
Logic, G (1.8/3.3V)			V			V							
Mixed-Signal, G (1.8/3.3V)			V			V							
Mixed-Signal GPIIA, G (1.8/5V)			V			V							
0.18 um: Part 1	Jan-7 TMMG01 Fab8 ZR	Feb-5 TMMG02 Fab3 Shirley	Mar-4 TMMG03 Fab5 CC	Apr-8 TMMG04 SSMC Lynn	May-6 TMMG05 Fab3 Jerry	Jun-3 TMMG06 Fab11 Jeff	Jul-1 TMMG07 Fab5 Francis	Aug-5 TMMG08 Fab11 FK	Sep-2 TMMG09 Fab3 Lynn	Oct-14 TMMG10 Fab10 YW	Nov-4 TMMG11 Fab3 Jeff	Dec-2 TMMG12 Fab11 Shirley	
Mixed-Signal/RF, G (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
Mixed-signal/RF, G (1.8/3.3V) embedded MTP	V	V	V	V	V	V	V	V	V	V	V	V	V
Mixed-signal/RF, G (1.8/3.3V) embedded OTP (Kilopass/eMemory)	V	V	V	V	V	V	V	V	V	V	V	V	V
Mixed Signal, G, (1.8/5V)	V	V	V	V	V	V	V	V	V	V	V	V	V
Logic, G (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
Logic, G (1.8/3.3V), Embedded OTP/ MTP	V	V	V	V	V	V	V	V	V	V	V	V	V
Logic, LV (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
Logic, LP (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
SiGe BICMOS, G (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
CMOS Image Sensor (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash(1K, 20K) (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash Enhanced (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash Enhanced (1.8/5V)	V	V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash HDR (1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash eLL(1.8/3.3V)	V	V	V	V	V	V	V	V	V	V	V	V	V
High Voltage (1.8/3.3/32V)	V	V	V	V	V	V	V	V	V	V	V	V	V
High Voltage (1.8/5/32V)	V	V	V	V	V	V	V	V	V	V	V	V	V
High Voltage, BCD (Generation-2)	V	V	V	V	V	V	V	V	V	V	V	V	V
High Voltage, BCD (Generation-3)	V	V	V	V	V	V	V	V	V	V	V	V	V
0.18 um: Part 2		Feb-12 TMMG13 Fab11 Jeff	Mar-11 TMMG14 Fab8 Jeff	Apr-22 TMMG15 Fab11 Lynn	May-13 TMMG16 Fab5 CC	Jun-17 TMMG17 Fab10 Shirley	Jul-15 TMMG18 Fab6 Jerry	Aug-19 TMMG19 SSMC CC	Sep-9 TMMG20 Fab8 ZR	Oct-21 TMMG21 Fab5 Francis	Nov-11 TMMG22 Fab8 Jerry	Dec-18 TMMG23 Fab10 Shirley	
Mixed-Signal/RF, G (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
Mixed-signal/RF, G (1.8/3.3V) embedded MTP		V	V	V	V	V	V	V	V	V	V	V	V
Mixed-signal/RF, G (1.8/3.3V) embedded OTP (Kilopass/eMemory)		V	V	V	V	V	V	V	V	V	V	V	V
Mixed Signal, G, (1.8/5V)		V	V	V	V	V	V	V	V	V	V	V	V
Logic, G (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
Logic, G (1.8/3.3V), Embedded OTP/ MTP		V	V	V	V	V	V	V	V	V	V	V	V
Logic, LV (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
Logic, LP (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash(1K, 20K) (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash Enhanced (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash Enhanced (1.8/5V)		V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash HDR (1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
EmbFlash eLL(1.8/3.3V)		V	V	V	V	V	V	V	V	V	V	V	V
High Voltage (1.8/3.3/32V)		V	V	V	V	V	V	V	V	V	V	V	V
High Voltage (1.8/5/32V)		V	V	V	V	V	V	V	V	V	V	V	V
High Voltage, BCD (Generation-2)		V	V	V	V	V	V	V	V	V	V	V	V
High Voltage, BCD (Generation-3)		V	V	V	V	V	V	V	V	V	V	V	V
0.18 um: Part 3	Jan-13 TMMG24 Fab6 Jerry		Mar-18 TMMG25 Fab6 CC	Apr-28 TMMG26 Fab8 FK	May-20 TMMG27 Fab10 Jerry	Jun-22 TMMG28 Fab6 ZR	Jul-22 TMMG29 Fab8 ZR		Sep-16 TMMG30 Fab6 Lynn		Nov-25 TMMG32 Fab6 Jerry		
Mixed-Signal/RF, G (1.8/3.3V)	V		V	V	V	V	V		V		V		
Mixed-signal/RF, G (1.8/3.3V) embedded MTP	V		V	V	V	V	V		V		V		
Mixed-signal/RF, G (1.8/3.3V) embedded OTP (Kilopass/eMemory)	V		V	V	V	V	V		V		V		
Mixed Signal, G, (1.8/5V)	V		V	V	V	V	V		V		V		
Logic, G (1.8/3.3V)	V		V	V	V	V	V		V		V		
Logic, G (1.8/3.3V), Embedded OTP/ MTP	V		V	V	V	V	V		V		V		
Logic, LV (1.8/3.3V)	V		V	V	V	V	V		V		V		
Logic, LP (1.8/3.3V)	V		V	V	V	V	V		V		V		
EmbFlash(1K, 20K) (1.8/3.3V)	V		V	V	V	V	V		V		V		
EmbFlash Enhanced (1.8/3.3V)	V		V	V	V	V	V		V		V		
EmbFlash Enhanced (1.8/5V)	V		V	V	V	V	V		V		V		
EmbFlash HDR (1.8/3.3V)	V		V	V	V	V	V		V		V		
EmbFlash eLL(1.8/3.3V)	V		V	V	V	V	V		V		V		
High Voltage (1.8/3.3/32V)	V		V	V	V	V	V		V		V		
High Voltage (1.8/5/32V)	V		V	V	V	V	V		V		V		
High Voltage, BCD (Generation-2)	V		V	V	V	V	V		V		V		
High Voltage, BCD (Generation-3)	V		V	V	V	V	V		V		V		
0.25 um	Jan-7 TMMF59 Fab10 Vincent	Feb-5 TMMF60 Fab8 YW	Mar-11 TMMF61 Fab10 YW	Apr-8 TMMF62 Fab10 YW		Jun-3 TMMF63 Fab8 YW	Jul-9 TMMF70 Fab10 YW		Sep-2 TMMF72 Fab8 YW		Nov-4 TMMF73 Fab10 YW		
Logic, G (2.5/3.3V, 2.5/5V)	V	V	V	V		V	V		V		V		
Mixed-Signal/RF, G (2.5/3.3V, 2.5/5V)	V	V	V	V		V	V		V		V		
High Voltage, BCD (2.5/5/12/24/40V/Vg2.5/5V)	V	V	V	V		V	V		V		V		
High Voltage, BCD (2.5/5/12/24/40V/Vg2.5/5/12V)	V	V	V	V		V	V		V		V		
High Voltage, BCD (2.5/5/60V/Vg 2.5/5V)	V	V	V	V		V	V		V		V		
High Voltage, BCD (2.5/5/12/24/40/60V/Vg2.5/5/12V)	V	V	V	V		V	V		V		V		
High Voltage, Gen-2 BCD (2.5/5/7/12/20/24/40/45/60V/Vg 2.5/5/12V)	V	V	V	V		V	V		V		V		
0.35 um: Part 1	Jan-13 TMMF32 Fab10 YW		Mar-23 TMMF33 Fab3 YW		May-6 TMMF34 Fab10 FK			Aug-19 TMMF36 Fab3 YW			Nov-11 TMMF37 Fab10 ZR		
Logic, G, Polycide/Silicide (3.3/5V)	V		V		V			V			V		
Mixed-Signal, G (3.3/5V)	V		V		V			V			V		
High Voltage, G, DDD (3.3/12/13.5)	V		V		V			V			V		
High Voltage, DDD (3.3/12/13.5/15/18V)	V		V		V			V			V		
High Voltage, BCD (3.3/20/23/Vg3.3V)	V		V		V			V			V		
High Voltage, BCD (3.3/5/12/15/20/40V/Vg3.3/5/12V)	V		V		V			V			V		
0.35 um: Part 2		Feb-19 TMMF38 Fab3 YW			May-20 TMMF39 Fab3 YW				Sep-23 TMMF93 Fab3 Vincent		Nov-18 TMMG94 Fab3 YW		
SiGe BICMOS, G (3.3V)		V			V				V		V		
0.5 um: Part 1			Mar-4 TMMF51 Fab3 Shirley			Jun-17 TMMF52 Fab3 YW			Sep-9 TMMF53 Fab3 CC			Dec-9 TMMF54 Fab3 YW	
High Voltage, (5/20/450/600/700/800V)			V			V			V			V	
0.5 um: Part 2		Feb-19 TMMF56 Fab2 FK											
High Voltage, GaN (650V)		V											
High Voltage, GaN (100V)		V											

* the calendar is Taiwan time

Please email cybershuttle@tsmc.com

Special Note (*)

1. tsmc owns the right to adjust shuttle plan and will inform customer about the change in 3 months ahead.

Change History :

1. Publish 2H2020 CyberShuttle schedule v1.6